Technical and Economical Performances of Photovoltaic Generation Façades

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Abstract- This paper presents an experimental investigation on the economical contribution given by a vertical-mounted PV system, which is placed on a façade of a building, replacing the traditional windows or glass-cement walls with active elements. The purpose of this work is to perform a comparison between the performances of next-generation systems and the traditional ones. Several systems have been tested and compared, obtaining promising results both in terms of efficiency and fill factor.

Keywords PV modules, DSSC, thin film silicon, building integrated photovoltaic.

1. Introduction

Nowadays, more of 40% of the world Carbon Dioxide (CO2) emissions are caused by the air conditioning, the heating and electric power systems of buildings. Thus, the optimization of their performances and the reduction of building consumptions can significantly contribute to increase the sustainability of our planet, trying to fit the International Energy Agency (IEA) requirements, with a perspective of a 80% of reduction by 2050 regarding the global emissions [1].

In this context, it is important to provide a refurbishment of the existing buildings, which can be generally obtained by means of two different methodologies:

- Passive methods, consisting of a reduction of the demand for both heating and cooling;
- Active methods, concerning the installation of low-energy equipment/technologies and the adoption of renewable energy generation systems.

With regards to the latest, a significant reduction of both heat and cooling losses could be provided by replacing the traditional windows with next-generation photovoltaic walls [2-4]. Furthermore, the new technology of PV systems, namely third generation and realized with DSSC (dye-sensitized solar cell) [5], is designed to be more suitable for architectural integration [6]. In addition, due to their bifacial feature, the adoption of DSSC cells can efficiently convert the light coming from both the indoor and the outdoor environments. Therefore, a possible application of these next-generation panels is to replace the glass of windows, reducing the silicon in thin layers, so that the transparency of the support is guaranteed.

This paper presents an experimental investigation and performance comparison of two technologies, DSSC and thin-film silicon, when adopted as photovoltaic façades. The advantages of such technologies are evaluated in terms of efficiency, costs and fill factor. The paper in [12] describes the evaluation of the performances of a DSSC system by thickness variation of nanocrystalline TiO2 for 8.13, 16.5, 26.7 and 32.2 μm.

More in detail, the work is structured as follows:
Section 2 reports an historical description and the actual scenario regarding the building-integrated photovoltaic technology.

Section 3 describes the PV structures adopted as façades.

Section 4 describes the experimental set-up for the measurement of the main electrical quantities involved in the system.

Section 5 compares the performances obtained by the PV technologies

Section 6 draws the technical and economical conclusions on the advantages of using PV systems as façades.

2. The Development of Solar Technology in BIPV

Building integrated photovoltaic (BIPV) systems play a fundamental role in the reduction of pollutants: they are able to produce energy where it is needed, playing an essential part in the development of zero-energy buildings. New features such as colors and aesthetic design, flexible and transparent shells, are concurring to reduce the barriers posed against the spread of BIPV systems.

BIPVs employ PV materials in order to substitute the conventional bulk building materials, which are part of the building covers, i.e. the roofs, walls and windows. In such a way, BIPV are considered as a functional part of the building structure, due to their dual role: envelope structure and power generation. Therefore, they are increasingly integrated into the design of the building in the first stages, no longer in later phases of refurbishing. The BIPV system serves as building envelope material and power generator simultaneously and it has a great advantage compared to non-integrated PV systems, because there is neither need for allocation of additional space nor reduction and adaption in building added photovoltaic (BAPV).

The next subsections present both the evolution of photovoltaic technologies and the diffusion in architectural integration.

2.1. First Generation of PV in BIPV

Single junction solar cells based on silicon wafers made the first generation of PV cell technology. The panel is massive, thick, the color, always the same, announces the operation of a new technology, which does not make compromise with the external environment and aesthetic integration. The first generation of PV systems in BIPV (sometimes BAPV) mounts directly onto the roof of building and sometimes in the façade, as shown figure 1.

Rigid structures characterize the first generation PV, mainly crystalline silicon (c-Si) PV cells are employed, whose main parameters are hereinafter reported:
- Thicknesses high (about 0.2-0.5 mm);
- Efficiencies between 10 and 16%;
- Efficiency guaranteed twenty to thirty years;
- Consolidated know-how (on the market since the 70s);
- Current costs: approx. 3000-4500 € / kWp installed.

Sometimes the high cost of the panels forces economics in integration solutions, so reducing the aesthetic and the integration.

![Fig. 1. First examples of BIPV on exiting building (a), on a new construction.](image1)

In order to reduce the costs, the polycrystalline (poly-Si) technology was developed. Poly-silicon is produced by employing an upgraded metallurgical-grade silicon, using metallurgical instead of chemical purification processes. Due to the non-uniform tonality, poly-Si modules are not well suited to architectural integration.

2.2. Second Generation of PV in BIPV

As mentioned before, single junction devices drive the second generation of photovoltaic technologies, but with the aim of using less active material to equate or approximate the efficiencies of first generation.

Second-generation photovoltaic solar cells use amorphous (a-Si), Cadmium telluride/cadmium sulphide (CdTe/CdS), Copper indium gallium diselenide (CIGS) or polycrystalline-Si (p-Si) deposited on low-cost substrates, such as glass.

These technologies benefit from the fact that CdTe, CIS and a-Si absorb the solar spectrum better than C-Si and poly-
Si, allowing a reduction of active material, whose main parameters are here reported:

- Low thicknesses (about 10-100 μm), possible flexible panels;
- Efficiencies between 6 and 10%;
- Guaranteed efficiency 15-20 years;
- Know-how in consolidation (first products commercials for just over fifteen years).

Figure 2 shows how the second PV generation intervention has contributed to the decrease in costs as pieces increase.

A thin-film of amorphous silicon solar PV cells is obtained by deploying several layers of photovoltaic solar cell materials onto a substrate. A thin film can also be deposited at very low temperatures, as low as 75°C, which allows the deposition on plastic support in order to realize curved structures, such as the one shown in figure 3.

2.3. Third Generation of PV in BIPV

Third-generation photovoltaic cells inherited from the second one the deposition methods and the thin film, trying the reduction of costs by employing low cost materials and by increasing the surface of active material. The aim is to achieve high-efficiency of second-generation, but employing more and more materials that are both nontoxic and not limited in abundance. The related main features can be summarized as follows:

- Theoretically achievable efficiencies: 25% and above;
- Current phase: study of models and operational research;
- Materials presumably used: inorganic

Figure 4 shows the objectives of the third generation of PV: in order to increase the diffusion of generation systems, to rethink each surface as an improved surface, or to generate energy or to manage thermal transmission, the price reduction should be able to increase the occupied area.

2.3.1. Dye-sensitized Solar Cells (DSSC)

The dye-sensitized solar cell (DSSC) was originally invented in 1988 by Brian O’Regan and Michael Gratzel at UC Berkeley [5]. It is a low-cost solar cell belonging to the group of thin film solar cells.

The DSSC has a number of attractive features, such as:

- it is semi-flexible and semi-transparent offering a variety of new uses, ignored by rigid support systems;
- most of the materials used are low-cost and abundant in nature;
- density of short circuit current Jsc is about 20 mA/cm2;
- open circuit voltage Voc is about 0.7 V;
- efficiency η is 10-12%;
- stability problems at high temperatures (above 70 °C), but stable up to 60-65 °C
- ideal for low-cost and high-volume production;
- stability problems related to the use of liquid redox mediators, need to find solid mediators;
- efficiencies expected in 5-10 years over 20%;
- good performances even with diffused light;
- it is necessary to develop less expensive and less polluting dyes than the present ones (based on heavy metals).
Figure 5 represents the working scheme of a DSSC.

![Diagram of DSSC](image)

**Fig. 5.** Representation of the operation of a DSSC.

1) An inorganic semiconductor nanocrystalline is deposited on a transparent electrode and coated with one monomolecular dye layer organic. All elements are immersed in one liquid electrolyte, in which one redox mediator is dissolved.

2) An organic dye, hit by a solar ray, produces an excited state (electron + lacuna); the electron is injected into the conduction band of the inorganic semiconductor, while the lacuna remains on the dye, which oxidizes (loses an electron).

3) The redox mediator provides the electron missing the dye, it is oxidized to its time.

4) The electron previously injected in the semiconductor reaches the anode and passes into the electric circuit to feed load.

5) An electron flows from the cathode in the electrolyte to reduce the oxidized mediator, thus closing the circuit.

DSSCs can vary the dye and make different colouring, to ensure greater architectural integration.

### 2.3.2. **BIPV Structures**

Third generation of PV allows to create different products: foil, tile, module and solar glazing. Foil products show good features, they are flexible and lightweight, which allows the employment on roofs where excessive weights cannot be used.

Tiles can cover the whole roof or selected parts of it, in order to acquire special aesthetics; the old tile geometry can be reproduced to grant a pleasant retrofit of historical buildings. The third generation of PV module embraces the possibility to wear also different colors.

PV cell glazing products offer an unlimited assortment of choices for windows, facades, glassed and roofs; with different colors and transparencies, the aesthetics objectives can be joined without reducing the production. The solar PV cell glazing modules diffuse sunlight and offer protection from elements as a normal window. Figure 6 shows the different products.

![BIPV third generation products](image)

**Fig. 6.** BIPV third generation products.

### 3. **Vertical Wall Structures**

It has to be highlighted that the purpose of adopting PV windows can be summarized in three main objectives: production of electrical energy, transmission of light in the building and regulation of the heat transmission.

Semi-transparent modules are integrated inside a glass shell for the obtainment of shading solutions and the transparency must be balanced in order to maximize simultaneously the energy savings and the generation of electricity [9-11].

Three generation systems are used and compared, as shown in Fig. 7, which depicts the PV systems during their installation at the University of Palermo. More in detail, 8 series-connected DSSC modules (30x30 cm, Daunia Solar Cell Inc.), consisting of a wide striped and narrow lined design, are used for the glass panel assembly (see Fig.8).

![Photovoltaic generating façade set-up](image)

**Fig. 7.** Photovoltaic generating façade set-up.
As shown in Fig. 9, the two other systems are cells composed by amorphous silicon thin film (Onix Solar), with the same degree of transparency. All the proposed structures are subjected to shade during the afternoon, in which they receive only scattered light.

The open circuit voltages of the DSSC and the A-Si PV windows are equal to 23 and 48 V, respectively. These values are suitable for DC loads, but far from the ones used in domestic DC/AC converters.

With regards to architectonical integration, a DSSC integrated within a vertical glass block is considered [13], which is shown in Fig. 10. This structure can be imagined as the composition of 2 two different shells of transparent glass, which are joined together by the use of an opaque frame. The glass block guarantees transparency to radiation and ensures the mechanical function of the system with flat surfaces.

The adoption of such structure decreases the cell performances, due to the fact that the radiation effect on the DSSC surface is decreased by the presence of the glass. Moreover, the opaque element projects a shadow on the DSSC, limiting its performances as well.

4. Measurement Setup

The experimental test bench has been set-up in order to measure the performances of the proposed systems simultaneously. The measurement set-up for the acquisition of both voltages and currents is depicted schematically in Fig. 11. It mainly consists of:
- A low-noise/high-precision Source-Meter (Keithley 2420), whose function is to ensure a stable DC supply.
- A LabView interface, connected to the Source-Meter.
- A switch, used for triggering the measurement one by one for the three different windows.
- An Arduino microcontroller, used for the on/off control commands of the switch and which communicates with the Labview interface.

Fig. 11. Measurement setup.

The measurement of the open-circuit voltage for all the three structures is provided by the Source-Meter. The data are acquired by the Labview interface, which controls a current cycle measure that starts from the open circuit voltage increased by 0.5 volts, up to a voltage of -0.5 volts. This range is divided into 100 parts, so that for each module a set of measures developed on 100 acquisitions can be acquired.

The settling down of the modules is ensured by delaying the acquisition system. This automated system has been adopted for the modules characterization over several months. In addition, other important parameters, such as irradiation, room temperature and glass surface temperature were also sampled by means of the Arduino board.

4.1. Glass Block Performance Characterization

It has been already highlighted that the glass structure reduces the DSSC performances and shades the module during the day. By referring to Fig. 12, which depicts the sensors located at the glass block surface, these performance reduction can be evaluated by considering 15 different positions including the vertical edges (the 16th position is considered as reference value and it is outside of the structure).

The distribution of daylight in the glass block was performed by considering four exposures: south, north, east and west [14]. For instance, the distribution of the performance reduction for south and north exposure are depicted in Fig. 13.

There are clearer and darker areas. By reducing the DSSC performances in lighter areas is just appreciable (if the DSSC is placed close to the inner surface), while in the darker areas, there has been a reduction in yields of 10-20% (especially if the DSSC was kept in the middle of the shell).

Fig. 12. The 15 positions in which the sensors were placed inside the glass block, and a partially set-up of the Arduino microcontroller.

Fig. 13. Superficial shaded areas of glass block. On the left the southern exposure, on the right the northward.
5. Analysis of the PV Wall Performances

The data acquired from the test bench described in Section 4 have been processed and the I-V and P-V characteristics for each of the proposed system have been determined and plotted in Figs 14-19. These data consider measurements in different days (three during the morning and three during the afternoon) with different levels of solar radiation. Since the proposed windows are exposed towards east, the results show higher production during the first hours of the related day.

The trends refer to a sunny day of July with a good solar radiation in order to obtain a high power output and reliable current-voltage curves. An initial value of solar irradiation of 715 W/m² and a final value of 68 W/m² were detected.

![DSSC - PV curves](image1)

**Fig. 14.** Power-voltage profiles of the DSSC cell at various levels of irradiance.

![DSSC - IV curves](image2)

**Fig. 15.** Current-voltage profiles of the DSSC cell at various levels of irradiance.

![Silicon Blue - PV curves](image3)

**Fig. 16.** Power-voltage profiles of the blue silicon cell at various levels of irradiance.

![Silicon Blue - IV curves](image4)

**Fig. 17.** Current-voltage profiles of the blue silicon cell at various levels of irradiance.

The comparison of the previously reported trends leads to the result that the DSSC module produces less power than the silicon cells. Furthermore, the last ones have a higher open circuit voltage, allowing a better interfacing with power electronics systems, which require adequate voltage levels.

The a-Si generation system has an open circuit voltage of about 50 volts with high irradiation conditions, an adequate value for DC power supply, compared to the 23 volts of the DSSC generation system, which will require boost converters.

![Silicon Grey - PV curves](image5)

**Fig. 18.** Power-voltage profiles of the grey silicon cell at various levels of irradiance.

![Silicon Grey - IV curves](image6)

**Fig. 19.** Current-voltage profiles of the grey silicon cell at various levels of irradiance.
5.1. Comparison of the Results

In order to determine the performances of the three generation systems, a set of measurements to evaluate the produced power, fill factor and efficiency trends for each PV technology, have been carried out.

The produced power has been obtained from current and voltage measurements, subsequently determining the daily power profile and extracting the daily value of the maximum produced power. Figure 20 and Figure 21 show the produced power trend in the morning and afternoon for each PV technology. Figure 21 shows that the produced power by the DSSC is lower than the silicon cells during the morning, but has similar values in the afternoon hours.

The Fill Factor (FF) of a solar cell is essentially a measure of quality of the solar cell. It is calculated by comparing the maximum obtainable power (PM) to the theoretical power that would be output to the product of the open-circuit voltage (Voc) and short-circuit current (Isc):

\[
FF = \frac{P_M}{(V_{oc} \cdot I_{sc})} 
\]  

Figure 22 and Figure 23 show the fill factor profiles in the morning and afternoon of the three generation systems.

The efficiency is the ratio between the maximum power (PM) and irradiance power (Pin), evaluated by the product of the total area of the panel (0.72 m²) for the irradiance value (in this case was taken as reference to the irradiance value on vertical panel):

\[
\eta = \frac{P_M}{P_{in}} = \frac{FF \cdot (V_{oc} \cdot I_{sc})}{P_{in}} 
\]  

Figure 24 and Figure 25 show the efficiency profiles in the morning and afternoon of the three generation system.

The efficiency of silicon windows varies, an average of 1.5% was found in the morning and 1% in afternoon.
The performance of the DSSC cells improves in diffuse light in the afternoon, compared to direct light in the morning.

The low efficiency value (1.5%) of the a-Si is easily explained. A commercial panel of a first or second generation photovoltaic system normally has an efficiency of 10%, corresponding to azimuth inclination; when inclined by 90° (located on the façade of a building), it reduces its efficiency from its maximum value to a further 0.40 factor [15]. To gain in transparency, active material above the glass holder is progressively reduced; so, the transparency reduce the yield to 1.5%.

Instead, for the DSSC, useful values to compare the evaluated results, without considering the vertical disposition, can be found in the works of Han et al. [8], Kwak at al. [16], Peng at al. [17], Wang and Wong [18]. In their recent studies Han found a FF about 70%, Kwak about 63.67, Peng a variable between 55.5% to 77.7 dependig on the color, Wang and Wong a FF varying from 55.5% to 73.1 depending on the properties of electrolyte.

Similar performances can be found in [7], in the laboratories of Fraunhofer ISE the FFs and efficiencies of DSSC, a-Si and CIGS (copper indium gallium diselenide) were compared, DSSC again has shown worst performances than a-Si.

Some discussions on the degradation of the DSSC should be addressed, since during the test, the DSSC cells had a progressive color degradation, even becoming transparent in the last period of the measurements. This obvious phenomenon due to the not optimized sealing conditions, in our experiment, does not cause an excessive reduction of the electrical performances of the cells, but only provides an aesthetic alteration. The observed DSSC degradation is not due to a loss of electrolyte outward, but it is due to a “Photo induced Electrophoresis” occurring between adjacent cells due to non-hermetic sealing between the strips. More in detail, the light polarizes PV cells consecutively increasing voltages and if the strip electrolyte comes into contact with the neighbor, it creates a lateral drift and separation of ions I^-/I3^-, which results in an electrolyte color change in areas where iodine deficiency is present. Figure 26 shows a comparison of the cells in about four months of measures.

The phenomenon of progressive degradation of DSSCs is not new [19], but in this case to a macroscopic visual degradation does not correspond a degradation of electrical performances. To avoid this phenomenon, different researcher are focusing their efforts on the development of stable electrolytes [18]. A similar alteration of the DSSC has been reported in a very recent paper [8]; the authors discovered a power conversion efficiency reduction about 64% after 200 hours of exposition. Instead, Kwak discovered a reduction of efficiency about 73.5% after 1000 hours.

![Fig. 25. Efficiency profiles in the afternoon of the three generation systems.](image)

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![Fig. 26. DSSC cells degradation during measurements: a) initial, b) during and c) finished test.](image)
6. Discussion on realization of a façade

This section discusses the technical and economical parameters for the realization of a photovoltaic façade, both with transparent windows (3rd generation) and opaque panels (1st and 2nd generations).

It can be stated that the costs derived from the adoption of photovoltaic technologies strictly depend on the complexity of the used processes (chemicals, metallurgical or deployment layers): a-Si is a well developed technology, while DSSC just started during the third generation. Nevertheless, the process for the realization of a DSSC cell is less complicated with respect to the traditional PV panels, due to the fact simpler and minor operations have to be performed. Moreover, the energy required for high temperature processes is much lower. The only process that requires a heating of the material is the sintering process, while high temperatures are required by the processes of purification, doping, and deposition of the anti-reflective coating for the creation of a silicon cell. In addition, the process for silicon cell production is more complex due to the need of an extremely clean working environment. In this perspective, the costs for DSSCs should be much lower than those of the a-Si.

However, the production technologies required for DSSC are not fully developed in other industrial sectors, so there are no established technologies and energy-efficient process that allow reducing the payback time for an investment. From the economical point of view, the DSSC costs for their production are not easily findable.

Data on the cost of production of DSSC are not easily found in the literature. Kalowekamo et al [20] have updated the information reported in [21] and [22], estimating the theoretical ones.

**Table 1. Comparison of the proposed systems**

<table>
<thead>
<tr>
<th>Experimental</th>
<th>Technical literature</th>
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<tr>
<td>DSSC</td>
<td>Blue/grey</td>
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<tr>
<td>Efficiency</td>
<td>5%</td>
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<td>Vertical</td>
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<td>Surface [m²]</td>
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<td>Glassblock [€]</td>
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<td>M DSSC</td>
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7. Conclusions

In this paper, a technical and economical analysis of the performances of solar generating façade has been presented. Two technologies have been compared: DSSC and a-Si thin film solar windows and three system were directly tested (DSSC and blue and grey solar cell). A technical evaluation of the behavior of PV walls, in terms of generated power, efficiency and Fill Factor, have been considered in different hours and days.

From the comparison of the performance of the three systems, it is noted that the silicon cells, compared to the DSSC cells, have a produced power, fill factor and efficiency higher during the morning hours. However, DSSC cells have performances comparable with a silicon cell in the afternoon hours, in the presence of scattered light.

In particular, it is observed that in case of scattered light, the performances of the DSSC improve. The DSSC is, unfortunately, subjected to degradation phenomena, leading
to an increase of the transparency degree of the cell with obvious loss of color, even if it does not determine an excessive reduction of electrical performance of the cell.

In conclusion, the three types of cells exhibit a good degree of architectural integration in buildings, but at this moment the electrical performances in terms of power produced are far from contribute to the power requested by building in an economic form.

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